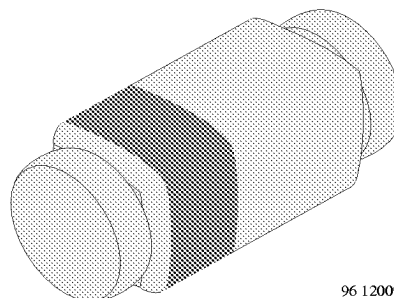




Silicon Epitaxial Planar Diodes

Applications

General purposes



96 12009

Absolute Maximum Ratings

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Type	Symbol	Value	Unit
Peak reverse voltage		BAV200	V_{RRM}	60	V
		BAV201	V_{RRM}	120	V
		BAV202	V_{RRM}	200	V
		BAV203	V_{RRM}	250	V
Reverse voltage		BAV200	V_R	50	V
		BAV201	V_R	100	V
		BAV202	V_R	150	V
		BAV203	V_R	200	V
Forward current			I_F	250	mA
Peak forward surge current	$t_p=1\text{s}, T_j=25^\circ\text{C}$		I_{FSM}	1	A
Forward peak current	$f=50\text{Hz}$		I_{FM}	625	mA
Junction temperature			T_j	175	$^\circ\text{C}$
Storage temperature range			T_{stg}	$-65\dots+175$	$^\circ\text{C}$

Maximum Thermal Resistance

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Symbol	Value	Unit
Junction ambient	on PC board 50mmx50mmx1.6mm	R_{thJA}	500	K/W

Electrical Characteristics

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Forward voltage	$I_F=100\text{mA}$		V_F			1	V
Reverse current	$V_R=50\text{V}$	BAV200	I_R			100	nA
	$V_R=100\text{V}$	BAV201	I_R			100	nA
	$V_R=150\text{V}$	BAV202	I_R			100	nA
	$V_R=200\text{V}$	BAV203	I_R			100	nA
	$T_j=100^\circ\text{C}$, $V_R=50\text{V}$	BAV200	I_R			15	μA
	$T_j=100^\circ\text{C}$, $V_R=100\text{V}$	BAV201	I_R			15	μA
	$T_j=100^\circ\text{C}$, $V_R=150\text{V}$	BAV202	I_R			15	μA
	$T_j=100^\circ\text{C}$, $V_R=200\text{V}$	BAV203	I_R			15	μA
Breakdown voltage	$I_R=100\mu\text{A}$, $t_p/T=0.01$, $t_p=0.3\text{ms}$	BAV200	$V_{(BR)}$	60			V
		BAV201	$V_{(BR)}$	120			V
		BAV202	$V_{(BR)}$	200			V
		BAV203	$V_{(BR)}$	250			V
Diode capacitance	$V_R=0$, $f=1\text{MHz}$		C_D		1.5		pF
Differential forward resistance	$I_F=10\text{mA}$		r_f		5		Ω
Reverse recovery time	$I_F=I_R=30\text{mA}$, $i_R=3\text{mA}$, $R_L=100\Omega$		t_{rr}			50	ns

Characteristics ($T_j = 25^\circ\text{C}$ unless otherwise specified)

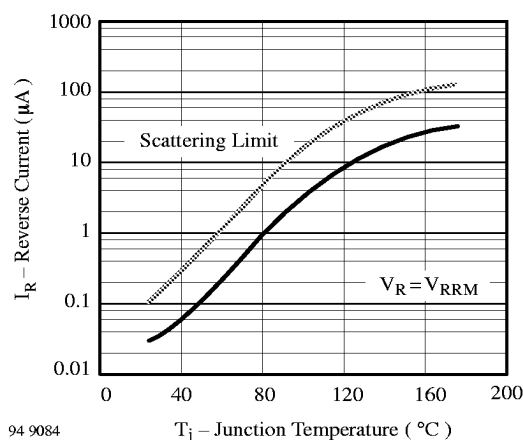


Figure 1. Reverse Current vs. Junction Temperature

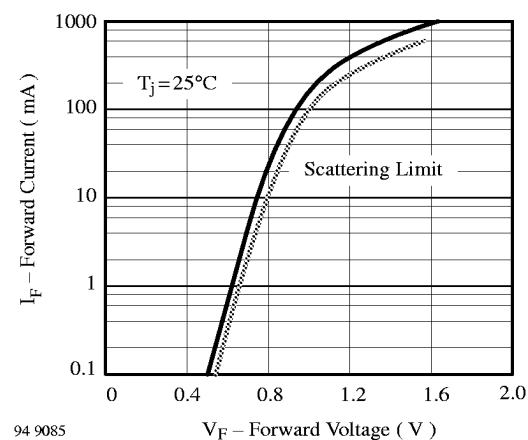


Figure 2. Forward Current vs. Forward Voltage

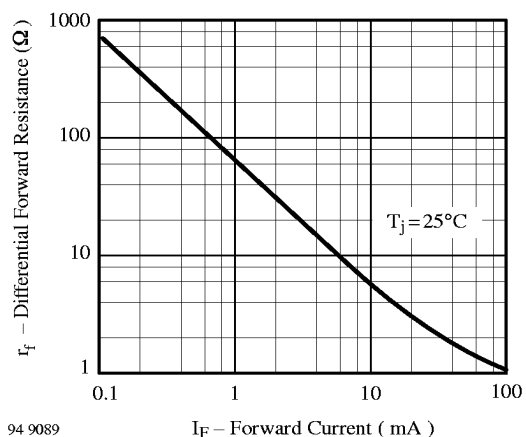
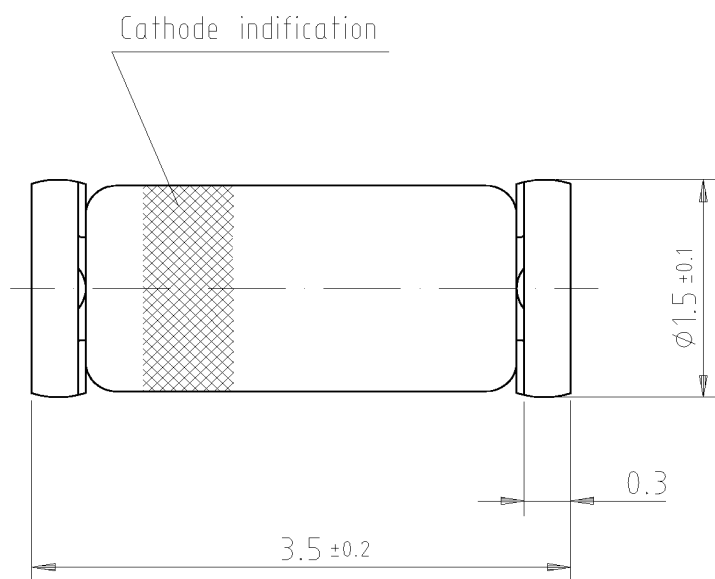
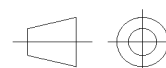
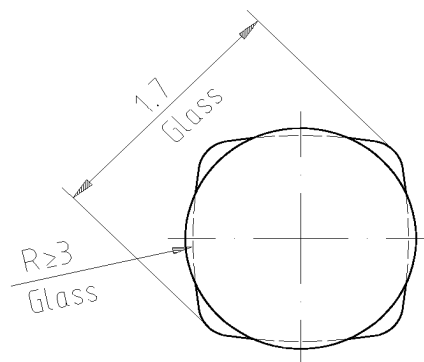


Figure 3. Differential Forward Resistance vs. Forward Current

Dimensions in mm



Glass case
Quadro MELF
similar to JEDEC 213 AA



technical drawings
according to DIN
specifications

96 12071